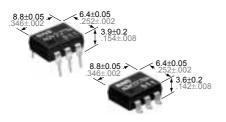




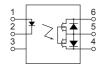
ideas for life

Lower output capacitance and on resistance. High speed switching. (Turn on time: 0.2ms, Turn off time: 0.08ms).

# RF PhotoMOS (AQV22ON)



mm inch



#### **FEATURES**

- 1. PhotoMOS relay with high response speed, low leakage current and low On resistance
- 2. Low capacitance between output terminals ensures high response speed:

The capacitance between output terminals is small, typically 10 pF. This enables for a fast operation speed of 200 us.

## 3. High sensitivity and low On resistance

Maximum 0.1 A of load current can be controlled with input current of 5 mA. The On resistance is less than our conventional models. With no metallic contacts, the PhotoMOS relay has stable switching characteristics.

#### 4. Low-level off state leakage current

The SSR has an off state leakage current of several milliamperes, whereas the PhotoMOS relay has only 30 pA even with the rated load voltage of 200 V (AQV227N).

- **5. Controls low-level analog signals** PhotoMOS relay features extremely low closed-circuit offset voltages to enable control of small analog signals without distortion.
- 6. Low terminals electromotive force (approx. 1  $\mu\text{V})$

#### TYPICAL APPLICATIONS

- Measuring devices
- · Scanner, IC checker, Board tester

#### **TYPES**

Туре	Output rating*			Par	Packing quantity			
			Through hole terminal	Surface-mount terminal				
	Load voltage	Load current			Tape and reel packing style			Tape and reel
			Tube packing style		Picked from the 1/2/3-pin side	Picked from the 4/5/6-pin side	Tube	
AC/DC type	200 V	70 mA	AQV227N	AQV227NA	AQV227NAX	AQV227NAZ	1 tube contains 50 pcs.	1,000 pcs.
	400 V	50 mA	AQV224N	AQV224NA	AQV224NAX	AQV224NAZ	1 batch contains 500 pcs.	

<sup>\*</sup>Indicate the peak AC and DC values.

Note: For space reasons, the package type indicator "X" and "Z" are omitted from the seal.

#### RATING

1. Absolute maximum ratings (Ambient temperature: 25°C 77°F)

	Symbol	Type of connection	AQV227N(A)	AQV224N(A)	Remarks		
Input	LED forward current	lF		50			
	LED reverse voltage	VR		5			
	Peak forward current	IFP		1	f = 100 Hz, Duty factor = 0.1%		
	Power dissipation	Pin		75			
Output	Load voltage (peak AC)	VL		200 V	400 V		
		l <sub>L</sub>	Α	0.07 A	0.05 A		
	Continuous load current		В	0.08 A	0.06 A	A connection: Peak AC, DC  B, C connection: DC	
			С	0.10 A	0.08 A	B, O conficction. Bo	
	Peak load current	I <sub>peak</sub>		0.21 A	0.15 A	A connection: 100 ms (1 shot), V <sub>L</sub> = DC	
	Power dissipation	Pout		360 mW			
Total power dis	Total power dissipation			410 mW			
I/O isolation voltage		Viso		1,500 V AC			
Temperature limits	Operating	Торг		<b>-40°C to +85°C</b> -40°F to +185°F		Non-condensing at low temperatures	
	Storage	Tstg		-40°C to +100°C -40°F to +212°F			

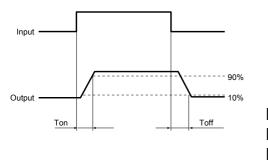
## RF PhotoMOS (AQV22ON)

2. Electrical characteristics (Ambient temperature: 25°C 77°F)

Item				Symbol	Type of connection	AQV227N(A)	AQV224N(A)	Remarks
	LED operate current		Typical	- I <sub>Fon</sub>	_	0.90 mA		I∟ = Max.
Input			Maximum	Ii-on		3.0 mA		
	LED turn off current		Minimum	Foff	_	0.4 mA		I∟ = Max.
			Typical			0.85 mA		
	LED dropout voltage		Typical	VF	_	1.25 V (1.14 V at I <sub>F</sub> = 5 mA)		I₅ = 50 mA
			Maximum			1.5 V		
	On resistance Typical		Typical	Ron	А	30 Ω	70 Ω	I <sub>F</sub> = 5 mA I <sub>L</sub> = Max. Within 1 s on time
Output			Maximum			50 Ω	100 Ω	
			Typical	Ron	В	16 Ω	55 Ω	I <sub>F</sub> = 5 mA I <sub>L</sub> = Max. Within 1 s on time
			Maximum			25 Ω	70 Ω	
		Typica			_	8 Ω	28 Ω	I <sub>F</sub> = 5 mA
			Maximum	Ron	С	12.5 Ω	35 Ω	I∟ = Max. Within 1 s on time
			Typical	_	_	10 pF		I <sub>F</sub> = 0 V <sub>B</sub> = 0 f = 1 MHz
	Output cap	acitance	Maximum	Cout		15 pF		
	Off state leakage current		Typical	M ILeak	_	30 pA 90 pA		I <sub>F</sub> = 0 V <sub>L</sub> = Max.
			Maximum			10 nA		
Transfer characteristics	Switching speed	Turn on time*	Typical	Ton	_	0.20 ms		I <sub>F</sub> = 5 mA I <sub>L</sub> = Max.
			Maximum			0.5 ms		
		Turn off time*	Typical	Toff	_	0.08 ms		I <sub>F</sub> = 5 mA I <sub>L</sub> = Max.
			Maximum			0.2 ms		
	I/O capacitance		Typical	Ciso		0.8 pF		f = 1 MHz V <sub>B</sub> = 0
			Maximum			1.5 pF		
	Initial I/O isolation resistance		Minimum	Riso	_	1,000 ΜΩ		500 V DC

Note: Recommendable LED forward current IF = 5mA.

\*Turn on/Turn off time

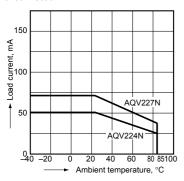


#### REFERENCE DATA

1. Load current vs. ambient temperature characteristics

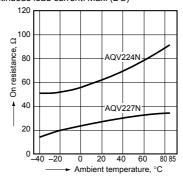
Allowable ambient temperature: -40°C to +85°C -40°F to +185°F

Type of connection: A



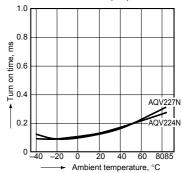
2. On resistance vs. ambient temperature characteristics

Measured portion: between terminals 4 and 6; LED current: 5 mA; Load voltage: Max. (DC); Continuous load current: Max. (DC)



3. Turn on time vs. ambient temperature characteristics

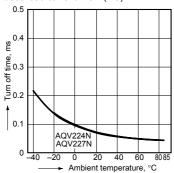
Sample: AQV227N, AQV224N; LED current: 5 mA; Load voltage: Max. (DC); Continuous load current: Max. (DC)



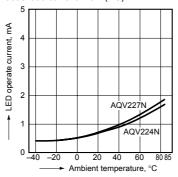
### RF PhotoMOS (AQV22ON)

4. Turn off time vs. ambient temperature characteristics

Sample: AQV227N, AQV224N; LED current: 5 mA; Load voltage: Max. (DC); Continuous load current: Max. (DC)

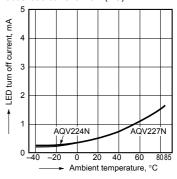


5. LED operate current vs. ambient temperature characteristics
Sample: AQV227N, AQV224N;
Load voltage: Max. (DC);
Continuous load current: Max. (DC)

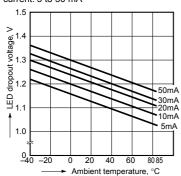


6. LED turn off current vs. ambient temperature characteristics

Sample: AQV227N, AQV224N; Load voltage: Max. (DC); Continuous load current: Max. (DC)

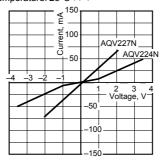


7. LED dropout voltage vs. ambient temperature characteristics Sample: All types; LED current: 5 to 50 mA

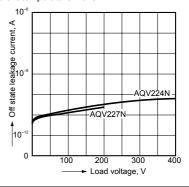


8. Current vs. voltage characteristics of output at MOS portion

Measured portion: between terminals 4 and 6; Ambient temperature: 25°C 77°F

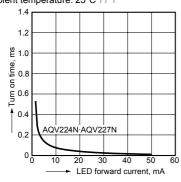


9. Off state leakage current Sample: AQV227N, AQV224N; Measured portion: between terminals 4 and 6; Ambient temperature: 25°C 77°F



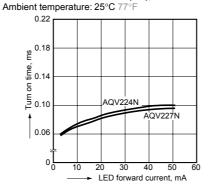
10. Turn on time vs. LED forward current characteristics

Sample: AQV227N, AQV224N; Measured portion: between terminals 4 and 6; Load voltage: Max. (DC); Continuous load current: Max. (DC); Ambient temperature: 25°C 77°F



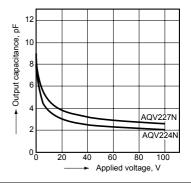
11. Turn off time vs. LED forward current characteristics

Sample: AQV227N, AQV224N; Measured portion: between terminals 4 and 6; Load voltage: Max. (DC); Continuous load current: Max. (DC);



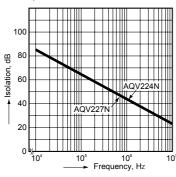
12. Output capacitance vs. applied voltage characteristics

Measured portion: between terminals 4 and 6; Frequency: 1 MHz, 30 mVrms; Ambient temperature:  $25^{\circ}C$   $77^{\circ}F$ 



13. Isolation characteristics (50  $\Omega$  impedance)

Measured portion: between terminals 4 and 6; Ambient temperature: 25°C 77°F



14. Insertion loss characteristics (50  $\Omega$  impedance)

Measured portion: between terminals 4 and 6; Ambient temperature: 25°C  $77^{\circ}F$ 

